



150V N-Channel Enhancement Mode MOSFET

Voltage

150 V

Current

40 A

Features

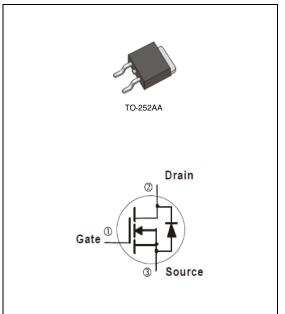
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_{D}@20A<35m\Omega$
- · High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	150	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	I _D	40	А	
	T _C =100°C		25		
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	120		
Power Dissipation	T _C =25°C	Po	131	W	
	T _C =100°C		52		
Continuous Drain Current	T _A =25°C	I _D	5.0	Α	
	T _A =70°C		4.0		
Power Dissipation	T _A =25°C	0	2.0	W	
Power Dissipation	T _A =70°C	Po	1.3		
Single Pulse Avalanche Energy (Note 6)		E _{AS}	31.5	mJ	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
— (Note 4.5)	Junction to Case	$R_{ heta JC}$	0.95	°C/W	
Typical Thermal Resistance ^(Note 4,5)	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA V _{DS} =V _{GS} , I _D =250uA	150	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$		2.0	3.0	4.0			
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =10V, I_D =20A	-	30	35	mΩ		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =120V, V _{GS} =0V	-	-	1.0	uA		
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	Qg	V _{DS} =120V, I _D =30A, V _{GS} =10V ^(Note 1,2)	-	52	-	nC		
Gate-Source Charge	Q_{gs}		-	10	-			
Gate-Drain Charge	Q _{gd}		-	19	-			
Input Capacitance	Ciss	V _{DS} =75V, V _{GS} =0V, f=1.0MHZ	-	2207	-	pF		
Output Capacitance	Coss		-	136	-			
Reverse Transfer Capacitance	Crss		-	58	-			
Turn-On Delay Time	td _(on)	$V_{DS}{=}75V, RL{=}1.7\Omega,$ $V_{GS}{=}10V, R_{G}{=}25\Omega$ (Note 1,2)	-	17	-	ns		
Turn-On Rise Time	t _r		-	100	-			
Turn-Off Delay Time	td _(off)		-	35	-			
Turn-Off Fall Time	t _f		-	106	-			
Drain-Source Diode								
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	40	А		
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.7	1.3	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.3mH, I_{AS} =14.5A, V_{DD} =25V, V_{GS} =10V
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

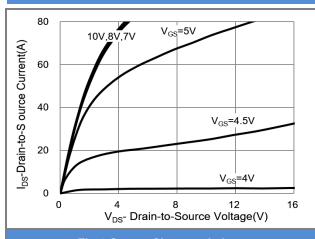


Fig.1 Output Characteristics

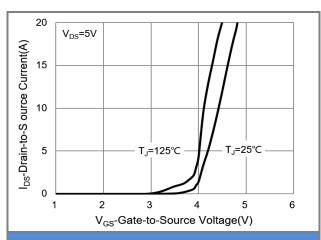


Fig.2 Transfer Characteristics

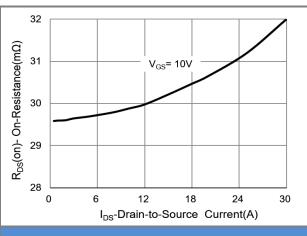


Fig.3 On-Resistance vs. Drain Current

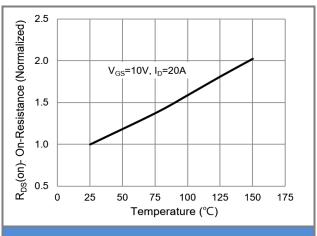
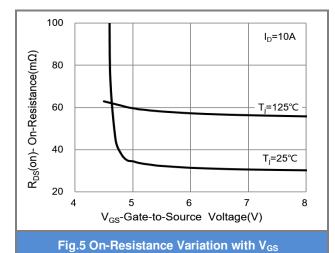


Fig.4 On-Resistance vs. Junction temperature



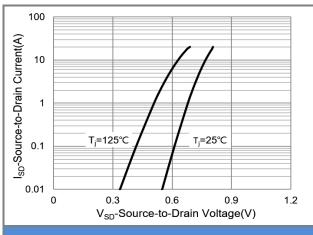


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

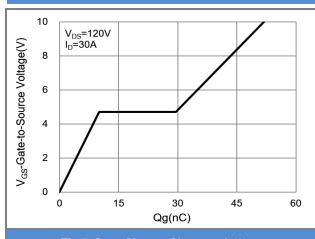


Fig.7 Gate-Charge Characteristics

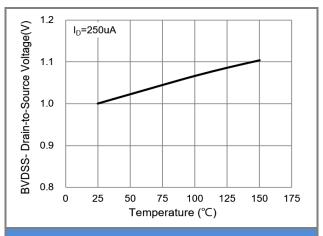


Fig.8 Breakdown Voltage Variation vs. Temperature

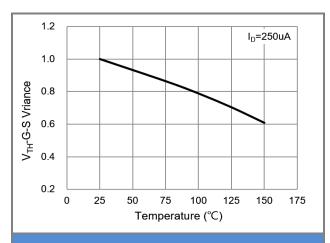


Fig.9 Threshold Voltage Variation with Temperature

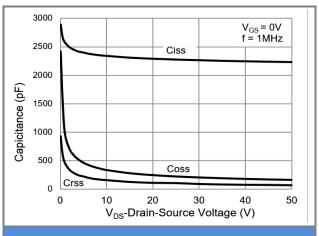
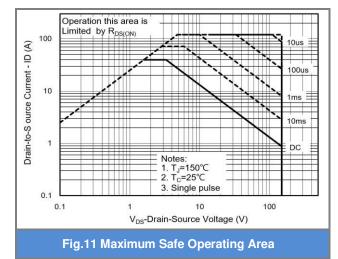


Fig.10 Capacitance vs. Drain-Source Voltage



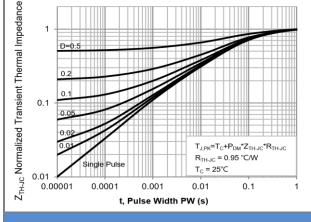


Fig.12 Normalized Thermal Transient Impedance

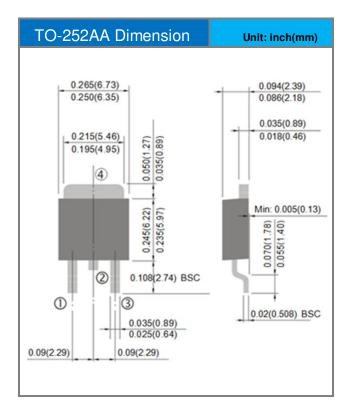


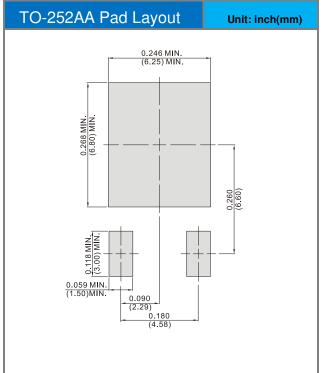


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJD40N15_L2_00001	TO-252AA	3,000pcs / 13" reel	D40N15	Halogen free	

Packaging Information & Mounting Pad Layout









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